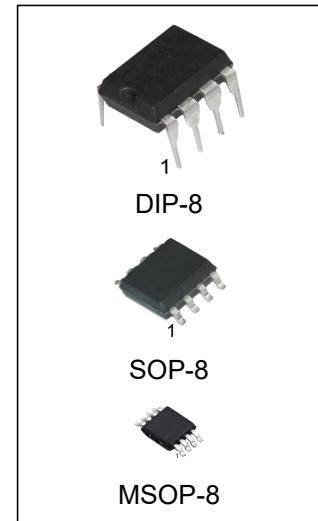


LM741 Operational Amplifier

General Description

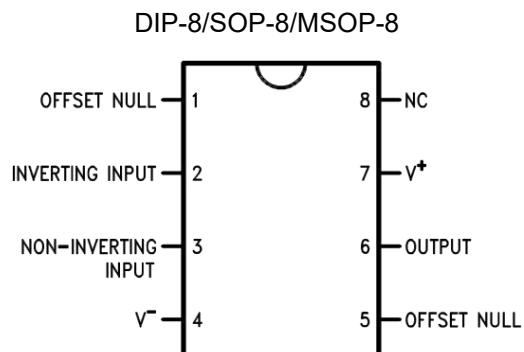
The LM741 series are general purpose operational amplifiers which feature improved performance over industry standards like the LM709. They are direct, plug-in replacements for the 709C, LM201, MC1439 and 748 in most applications. The amplifiers offer many features which make their application nearly foolproof: overload protection on the input and output, no latch-up when the common mode range is exceeded, as well as freedom from oscillations.



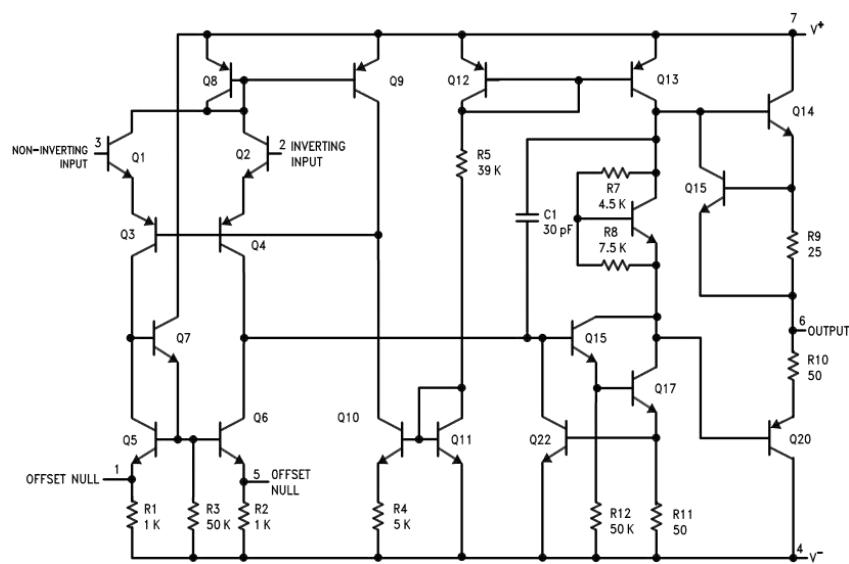
Ordering Information

DEVICE	PACKAGE TYPE	MARKING	PACKING	PACKING QTY
LM741N	DIP-8	LM741,741	TUBE	2000pcs/Box
LM741AN	DIP-8	LM741A,741A	TUBE	2000pcs/Box
LM741M/TR	SOP-8	LM741,741C	REEL	2500pcs/Reel
LM741AM/TR	SOP-8	LM741A,741AC	REEL	2500pcs/Reel
LM741MM/TR	MSOP-8	LM741,741C	REEL	3000pcs/Reel
LM741AMM/TR	MSOP-8	LM741A,741AC	REEL	3000pcs/Reel

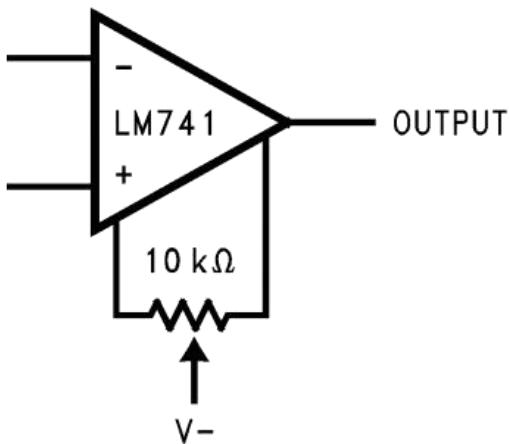
Connection Diagram



Schematic Diagram



Offset Nulling Circuit



Absolute Maximum Ratings⁽¹⁾

CONDITION	LIMITS
Supply Voltage	±18V
Power Dissipation ^(Note2)	500mW
Differential Input Voltage	±30V
Input Voltage ^(Note3)	±15V
Output Short Circuit Duration	Continuous
Operating Temperature Range	0°C to +70°C
Junction Temperature	150°C
Soldering Information (10 seconds)	260°C
Storage Temperature Range	-65°C to +150°C
ESD Tolerance	400V

Note1: "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits.

Note 2: For operation at elevated temperatures, these devices must be derated based on thermal resistance, and T_j max. (listed under "Absolute Maximum Ratings"). $T_j = TA + (\theta_{JA} PD)$.

Note 3: For supply voltages less than ±15V, the absolute maximum input voltage is equal to the supply voltage.

Thermal Resistance	DIP(N)	SOP-8(M)
θ_{JA} (Junction to Ambient)	100°C/W	195°C/W
θ_{JC} (Junction to Case)	N/A	N/A

Electrical Characteristics

Parameter	Conditions	LM741A			LM741			Units
		Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage	$T_A=25^\circ C$ $R_s \leq 10K\Omega$ $R_s \leq 50\Omega$		0.8	3.0		1.0	5.0	mW mW
	$T_{A\text{MIN}} \leq T_A \leq T_{A\text{MAX}}$ $R_s \leq 50\Omega$ $R_s \leq 10K\Omega$			4.0			6.0	mW mW
Average Input Offset Voltage Drift				15				$\mu V/^\circ C$
Input Offset Voltage Adjustment Range	$T_A=25^\circ C, V_s = \pm 18V$	± 10			± 15			mW
Input Offset Current	$T_A=25^\circ C$		3.0	30		20	200	nA
	$T_{A\text{MIN}} \leq T_A \leq T_{A\text{MAX}}$			70		85	500	nA
Average Input Offset Current Drift				0.5				$nA/^\circ C$
Input Bias Current	$T_A=25^\circ C$		30	80		80	500	nA
	$T_{A\text{MIN}} \leq T_A \leq T_{A\text{MAX}}$			0.21			1.5	μA
Input Resistance	$T_A=25^\circ C, V_s = \pm 18V$	1.0	6.0		0.3	2.0		$M\Omega$
	$T_{A\text{MIN}} \leq T_A \leq T_{A\text{MAX}}, V_s = \pm 18V$	0.5						$M\Omega$
Input Voltage Range	$T_A=25^\circ C$							V
	$T_{A\text{MIN}} \leq T_A \leq T_{A\text{MAX}}$				± 12	± 13		V
Large Signal Voltage Gain	$T_A=25^\circ C, R_L \geq 2K\Omega$ $V_s = \pm 18V, V_o = \pm 15V$ $V_s = \pm 15V, V_o = \pm 10V$	50			50	200		V/mW V/mW
	$T_{A\text{MIN}} \leq T_A \leq T_{A\text{MAX}}$ $R_L \geq 2K\Omega$ $V_s = \pm 18V, V_o = \pm 15V$							V/mW
	$V_s = \pm 15V, V_o = \pm 10V$	32			25			V/mW
	$V_s = \pm 5V, V_o = \pm 2V$	10						V/mW
Output Voltage Swing	$V_s = \pm 18V$ $R_L \geq 10K\Omega$ $R_L \geq 2K\Omega$	± 16						V V
	$V_s = \pm 15V$ $R_L \geq 10K\Omega$ $R_L \geq 2K\Omega$	± 15			± 12	± 14		V V
					± 10	± 13		
Output Short Circuit Current	$T_A=25^\circ C$	10	25	35		25		mA
	$T_{A\text{MIN}} \leq T_A \leq T_{A\text{MAX}}$	10		40				mA

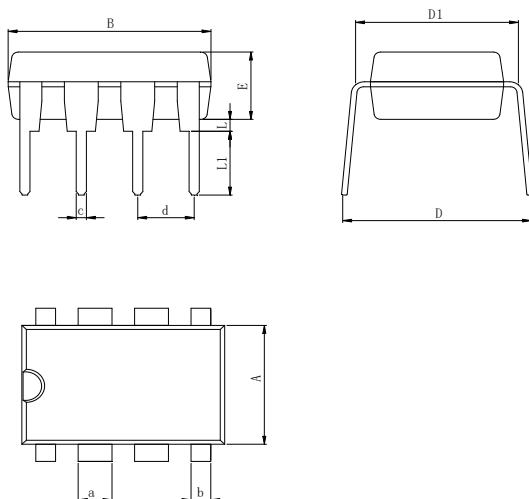
Common-Mode Rejection Ratio	T _A MIN≤T _A ≤T _A MAX R _S ≤10KΩ, V _{CM} =±12V R _S ≤50Ω, V _{CM} =±12V	80	95	0.5	70	90		dB dB
Supply Voltage Rejection Ratio	T _A MIN≤T _A ≤T _A MAX V _S =±18V to V _S =±5V R _S ≤50Ω R _S ≤10KΩ	86	96		77	96		dB dB
Transient Response Rise Time Overshoot	T _A =25°C, Unity Gain			0.25 6.0	0.8 20		0.3 5	μs %
Bandwidth ^(Note5)	T _A =25°C	0.437	1.5					MHz
Slew Rate	T _A =25°C, Unity Gain	0.3	0.7			0.5		V/μs
Supply Current	T _A =25°C					1.7	2.8	mA
Power Consumption	T _A =25°C V _S =±18V V _S =±15V		80	150		50	85	mw mw

Note 4: Calculated value from: BW (MHz) = 0.35/Rise Time(μs).

Note 5: Human body model, 1.5 kΩ in series with 100 pF.

Physical Dimensions

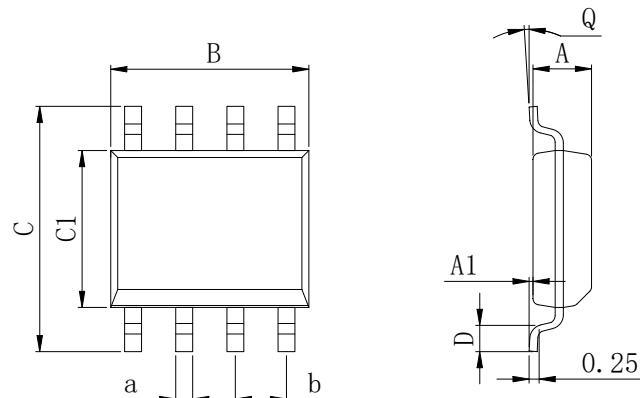
DIP-8



Dimensions In Millimeters(DIP-8)

Symbol:	A	B	D	D1	E	L	L1	a	b	c	d
Min:	6.10	9.00	8.10	7.42	3.10	0.50	3.00	1.50	0.85	0.40	2.54 BSC
Max:	6.68	9.50	10.9	7.82	3.55	0.70	3.60	1.55	0.90	0.50	

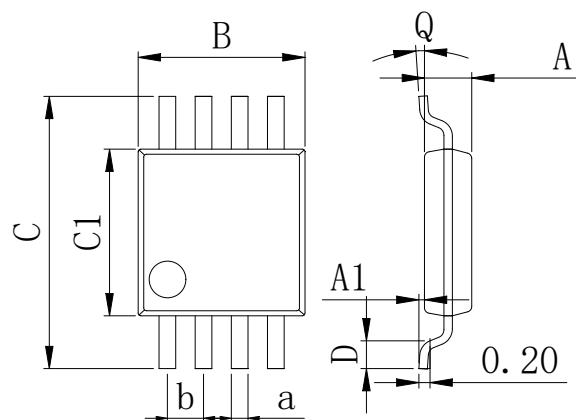
SOP-8



Dimensions In Millimeters(SOP-8)

Symbol:	A	A1	B	C	C1	D	Q	a	b
Min:	1.35	0.05	4.90	5.80	3.80	0.40	0°	0.35	1.27 BSC
Max:	1.55	0.20	5.10	6.20	4.00	0.80	8°	0.45	

MSOP-8



Dimensions In Millimeters(MSOP-8)									
Symbol:	A	A1	B	C	C1	D	Q	a	b
Min:	0.80	0.05	2.90	4.75	2.90	0.35	0°	0.25	0.65 BSC
Max:	0.90	0.20	3.10	5.05	3.10	0.75	8°	0.35	

Revision History

REVISION NUMBER	DATE	DESCRIPTION	PAGE
V1.0	2011-5	New	1-9
V1.1	2018-9	Update encapsulation type	1
V1.2	2022-4	Update Lead Temperature	3
V1.3	2024-12	Add a model marking name	1

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